

SOT-23


Pin Definition:

1. Gate
2. Source
3. Drain

PRODUCT SUMMARY

| V_{DS} (V) | $R_{DS(on)}$ (m Ω) | I_D (A) |
|--------------|----------------------------|-----------|
| -20 | 39 @ $V_{GS} = -4.5V$ | -4.7 |
| | 52 @ $V_{GS} = -2.5V$ | -4.1 |
| | 68 @ $V_{GS} = -1.8V$ | -2.0 |

Features

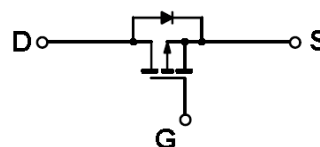
- Advance Trench Process Technology
- High Density Cell Design for Ultra Low On-resistance

Application

- Load Switch
- PA Switch

Ordering Information

| Part No. | Package | Packing |
|--------------|---------|-----------------|
| TSM2323CX RF | SOT-23 | 3Kpcs / 7" Reel |

Block Diagram


P-Channel MOSFET

Absolute Maximum Rating ($T_a = 25^\circ C$ unless otherwise noted)

| Parameter | Symbol | Limit | Unit |
|---|----------------|--------------------|------------|
| Drain-Source Voltage | V_{DS} | -20 | V |
| Gate-Source Voltage | V_{GS} | ± 8 | V |
| Continuous Drain Current, $V_{GS} @ 4.5V$. | I_D | -4.7 | A |
| Pulsed Drain Current, $V_{GS} @ 4.5V$ | I_{DM} | -20 | A |
| Continuous Source Current (Diode Conduction) ^{a,b} | I_S | -1.0 | A |
| Maximum Power Dissipation | P_D | $T_a = 25^\circ C$ | 1.25 |
| | | $T_a = 70^\circ C$ | 0.8 |
| Operating Junction Temperature | T_J | +150 | $^\circ C$ |
| Operating Junction and Storage Temperature Range | T_J, T_{STG} | - 55 to +150 | $^\circ C$ |

Thermal Performance

| Parameter | Symbol | Limit | Unit |
|--|-----------------|-------|--------------|
| Junction to Case Thermal Resistance | $R_{\theta JC}$ | 75 | $^\circ C/W$ |
| Junction to Ambient Thermal Resistance (PCB mounted) | $R_{\theta JA}$ | 250 | $^\circ C/W$ |

Notes:

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Electrical Specifications

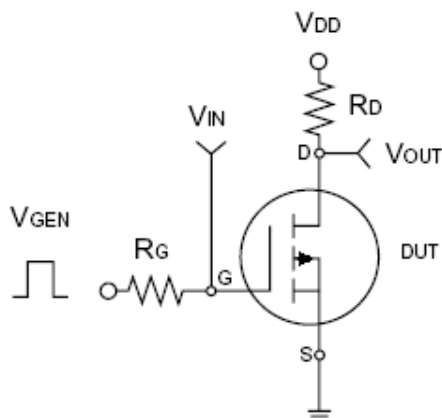
| Parameter | Conditions | Symbol | Min | Typ | Max | Unit |
|----------------------------------|--|--------------|------|------|-----------|------------|
| Static | | | | | | |
| Drain-Source Breakdown Voltage | $V_{GS} = 0V, I_D = -250\mu A$ | BV_{DSS} | -20 | -- | -- | V |
| Gate Threshold Voltage | $V_{DS} = V_{GS}, I_D = -250\mu A$ | $V_{GS(TH)}$ | -0.4 | -- | -1.0 | V |
| Zero Gate Voltage Drain Current | $V_{DS} = -16V, V_{GS} = 0V$ | I_{DSS} | -- | -- | -1.0 | μA |
| Gate Body Leakage | $V_{GS} = \pm 8V, V_{DS} = 0V$ | I_{GSS} | -- | -- | ± 100 | nA |
| On-State Drain Current | $V_{DS} \leq -5V, V_{GS} = -4.5V$ | $I_{D(ON)}$ | -20 | -- | -- | A |
| Drain-Source On-State Resistance | $V_{GS} = -4.5V, I_D = -4.7A$ | $R_{DS(ON)}$ | -- | 31 | 39 | m Ω |
| | $V_{GS} = -2.5V, I_D = -4.1A$ | | -- | 41 | 52 | |
| | $V_{GS} = -1.8V, I_D = -2.0A$ | | -- | 54 | 68 | |
| Forward Transconductance | $V_{DS} = -5V, I_D = -4.7A$ | g_{fs} | -- | 16 | -- | S |
| Diode Forward Voltage | $I_S = -1.0A, V_{GS} = 0V$ | V_{SD} | -- | -0.7 | -1.2 | V |
| Dynamic^b | | | | | | |
| Total Gate Charge | $V_{DS} = -10V, I_D = -4.7A, V_{GS} = -4.5V$ | Q_g | -- | 12.5 | 19 | nC |
| Gate-Source Charge | | Q_{gs} | -- | 1.7 | -- | |
| Gate-Drain Charge | | Q_{gd} | -- | 3.3 | -- | |
| Input Capacitance | $V_{DS} = -10V, V_{GS} = 0V, f = 1.0MHz$ | C_{iss} | -- | 1020 | -- | pF |
| Output Capacitance | | C_{oss} | -- | 191 | -- | |
| Reverse Transfer Capacitance | | C_{rss} | -- | 140 | -- | |
| Switching^c | | | | | | |
| Turn-On Delay Time | $V_{DD} = -10V, R_L = 10\Omega, I_D = -1A, V_{GEN} = -4.5V, R_G = 6\Omega$ | $t_{d(on)}$ | -- | 25 | 40 | nS |
| Turn-On Rise Time | | t_r | -- | 43 | 65 | |
| Turn-Off Delay Time | | $t_{d(off)}$ | -- | 71 | 110 | |
| Turn-Off Fall Time | | t_f | -- | 48 | 75 | |

Notes:

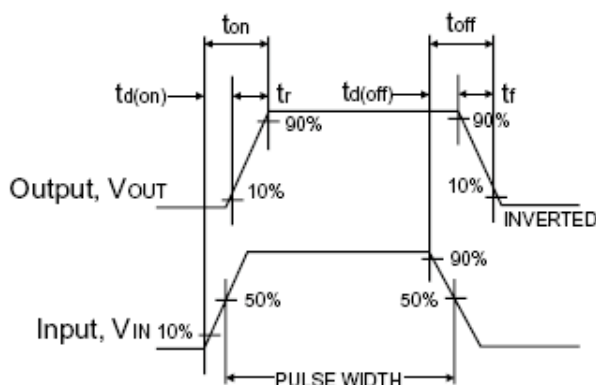
a. pulse test: $PW \leq 300\mu S$, duty cycle $\leq 2\%$

b. For DESIGN AID ONLY, not subject to production testing.

c. Switching time is essentially independent of operating temperature.



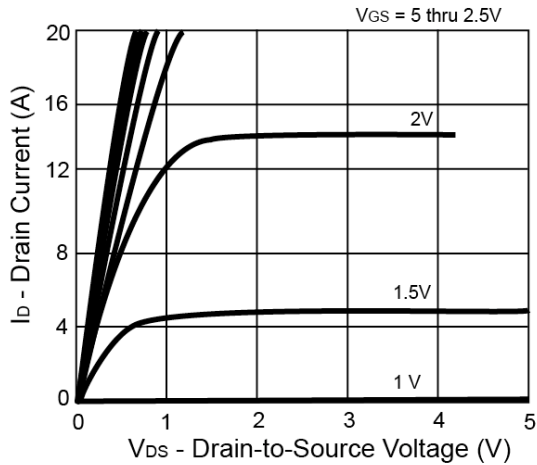
Switching Test Circuit



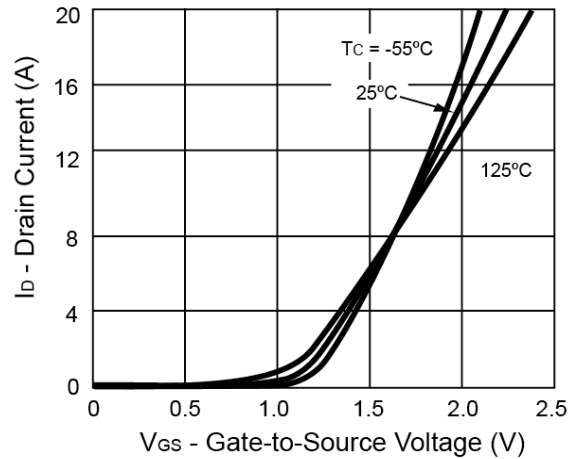
Switchin Waveforms

Electrical Characteristics Curve (Ta = 25°C, unless otherwise noted)

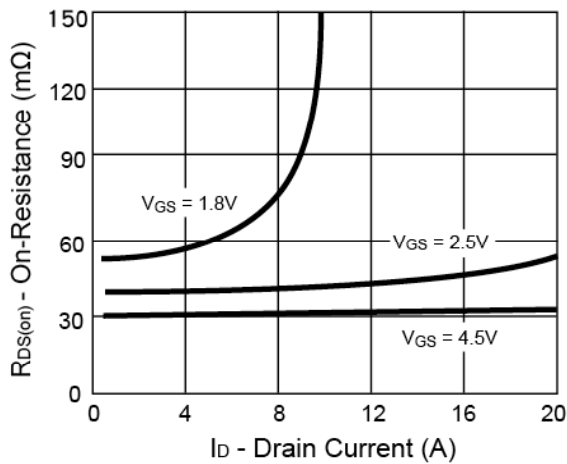
Output Characteristics



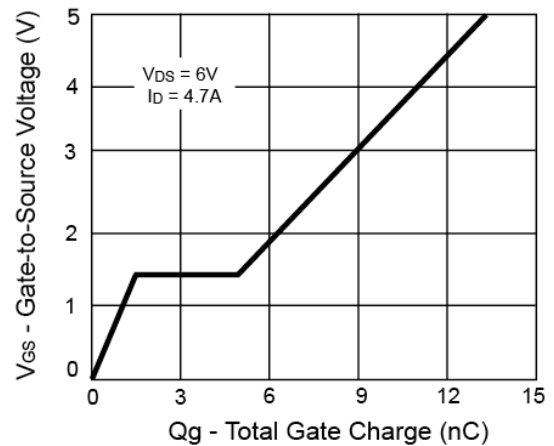
Transfer Characteristics



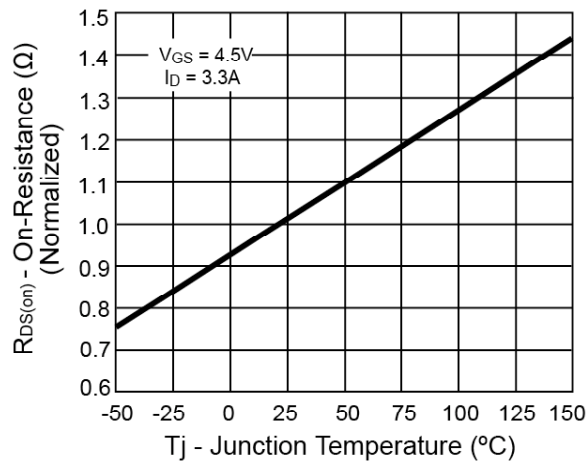
On-Resistance vs. Drain Current



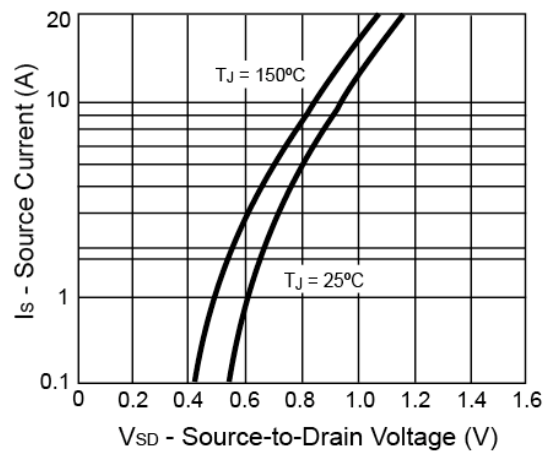
Gate Charge



On-Resistance vs. Junction Temperature

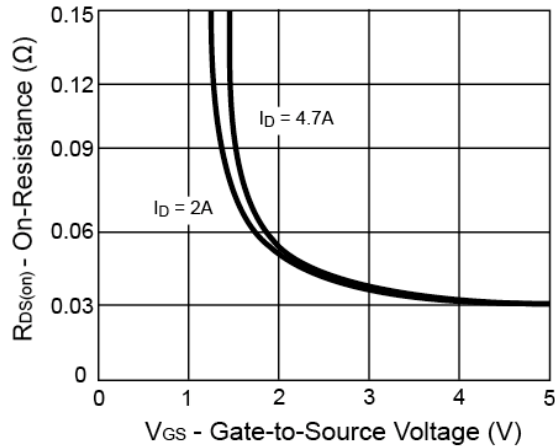


Source-Drain Diode Forward Voltage

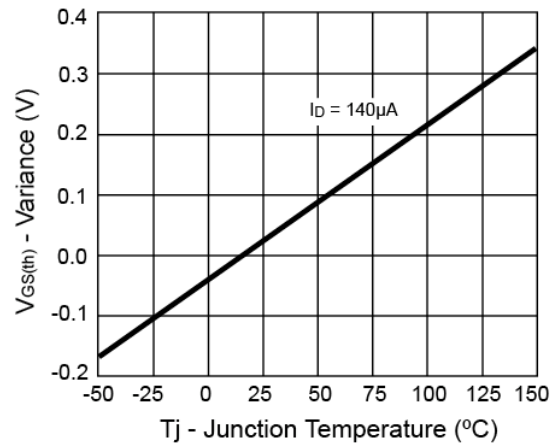


Electrical Characteristics Curve (Ta = 25°C, unless otherwise noted)

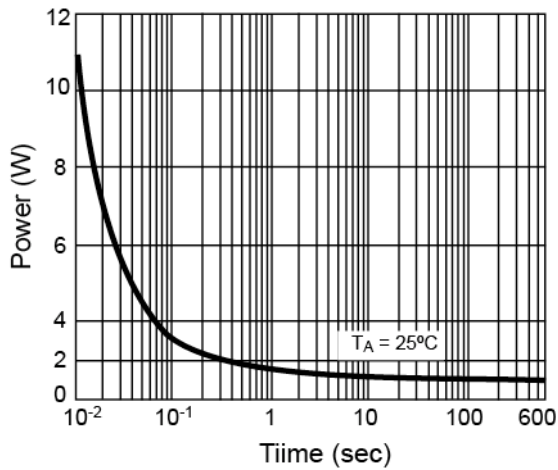
On-Resistance vs. Gate-Source Voltage



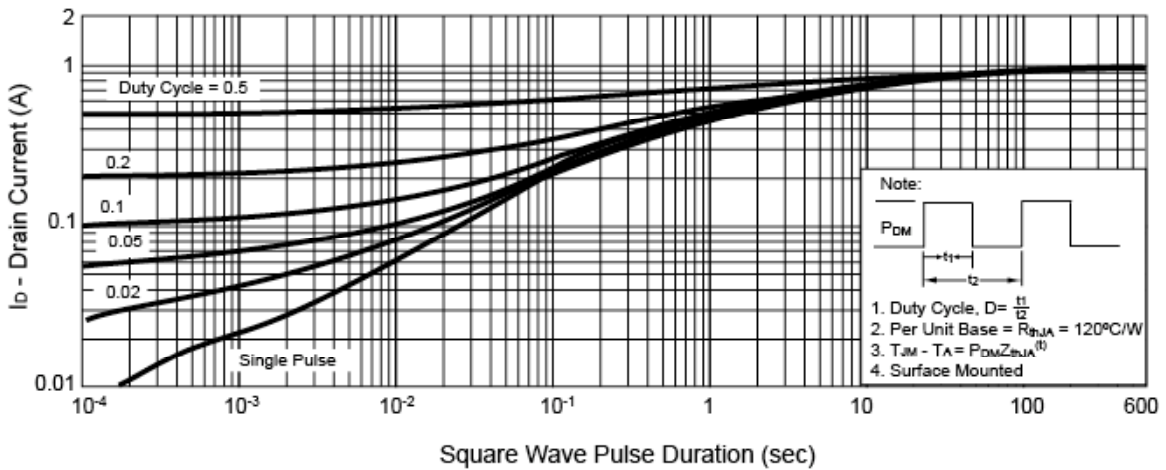
Threshold Voltage



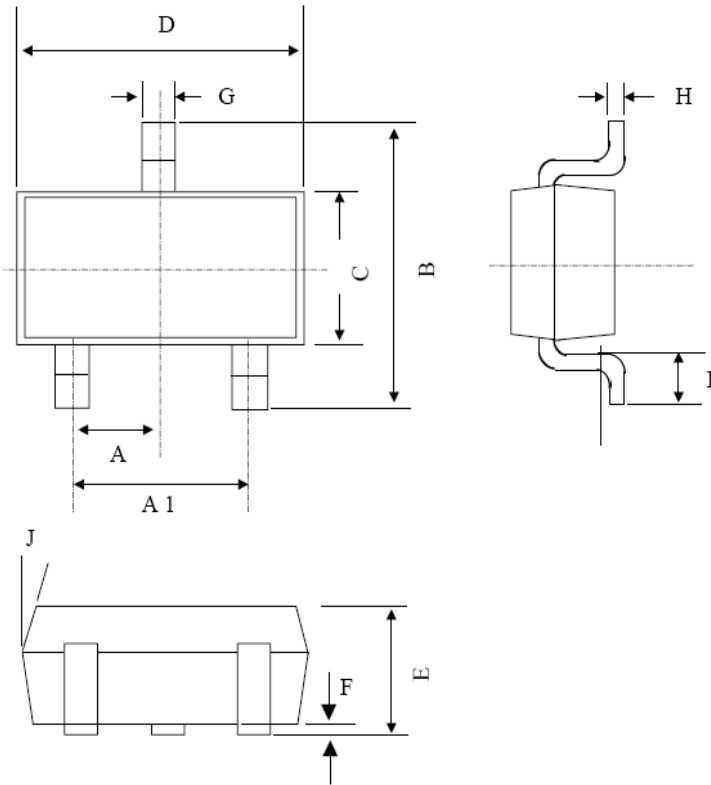
Single Pulse Power



Normalized Thermal Transient Impedance, Junction-to-Ambient

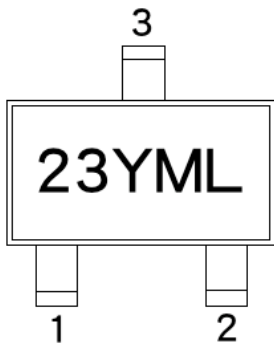


SOT-23 Mechanical Drawing



| SOT-23 DIMENSION | | | | |
|------------------|-------------|------|--------|-------|
| DIM | MILLIMETERS | | INCHES | |
| | MIN | MAX | MIN | MAX. |
| A | 2.88 | 2.91 | 0.113 | 0.115 |
| B | 0.39 | 0.42 | 0.015 | 0.017 |
| C | 1.78 | 2.03 | 0.070 | 0.080 |
| D | 0.51 | 0.61 | 0.020 | 0.024 |
| E | 1.59 | 1.66 | 0.063 | 0.065 |
| F | 1.04 | 1.08 | 0.041 | 0.043 |
| G | 0.07 | 0.09 | 0.003 | 0.004 |

Marking Diagram



- 23** = Device Code
- Y** = Year Code
- M** = Month Code
- (**A**=Jan, **B**=Feb, **C**=Mar, **D**=Apr, **E**=May, **F**=Jun, **G**=Jul, **H**=Aug, **I**=Sep, **J**=Oct, **K**=Nov, **L**=Dec)
- L** = Lot Code

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